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IMAN et al.

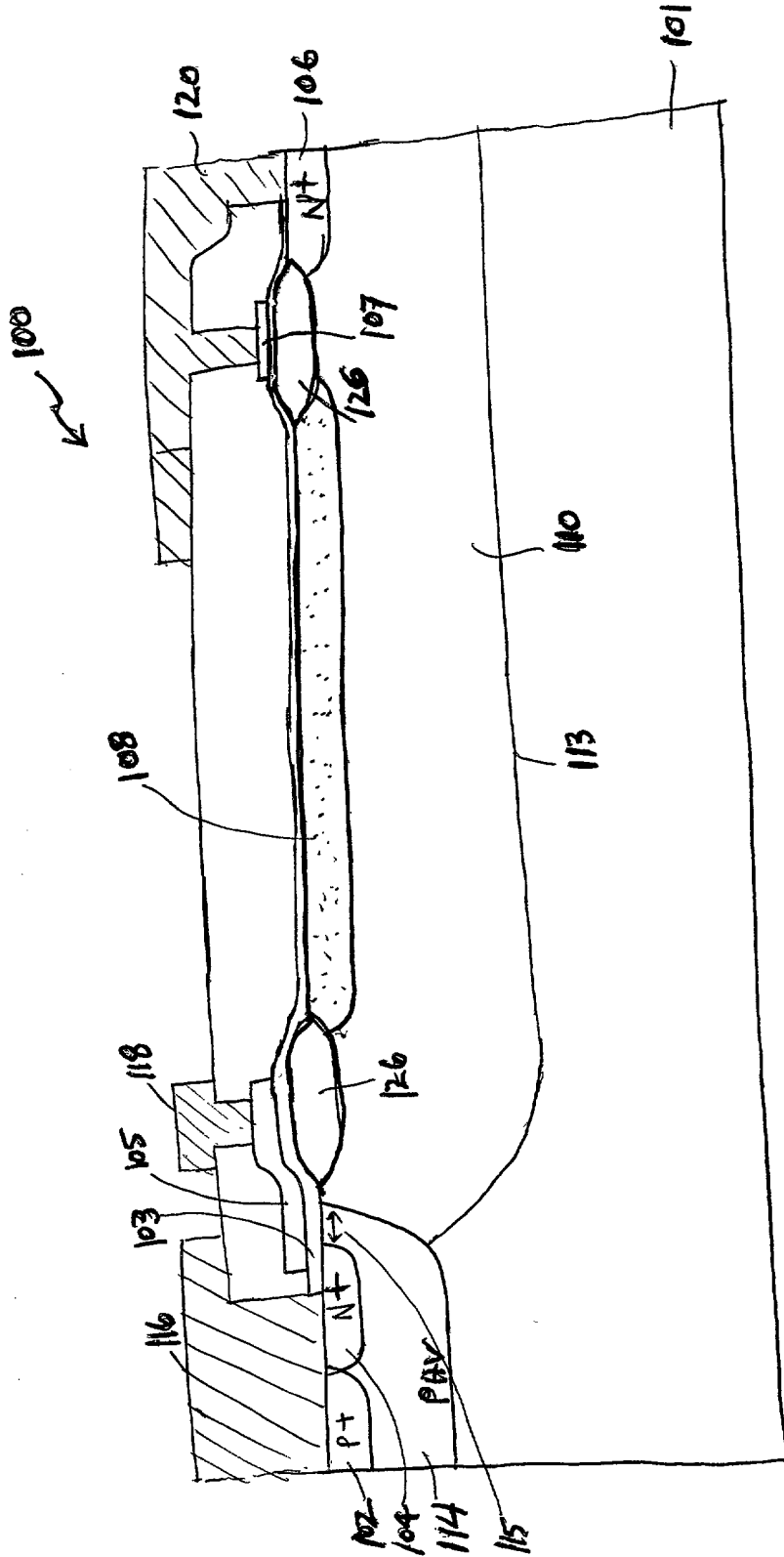


Fig. 1

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Title: METHOD FOR MANUFACTURING A HIGH VOLTAGE

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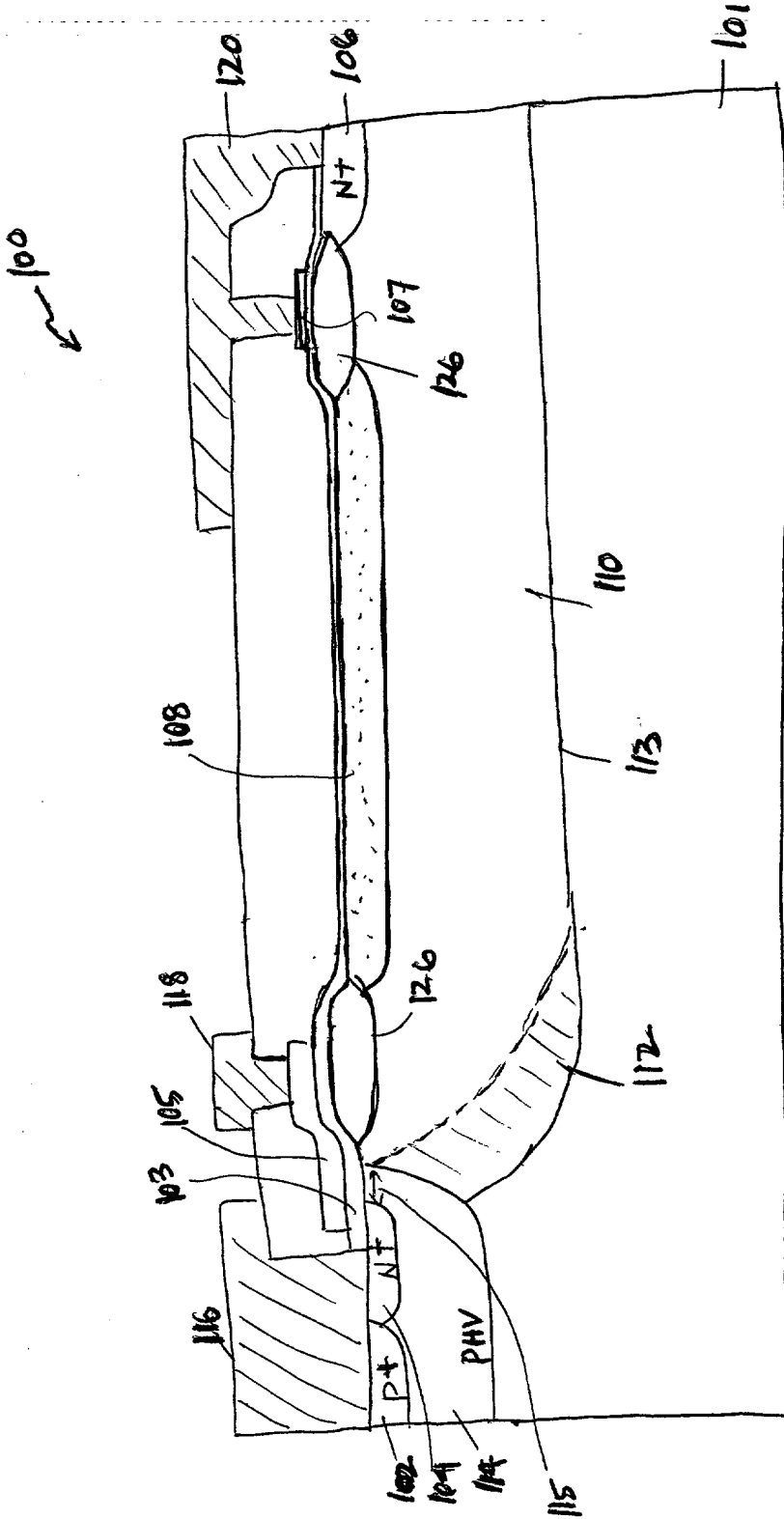


Fig. 2

Fig. 3

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Title: METHOD FOR MANUFACTURING A HIGH VOLTAGE

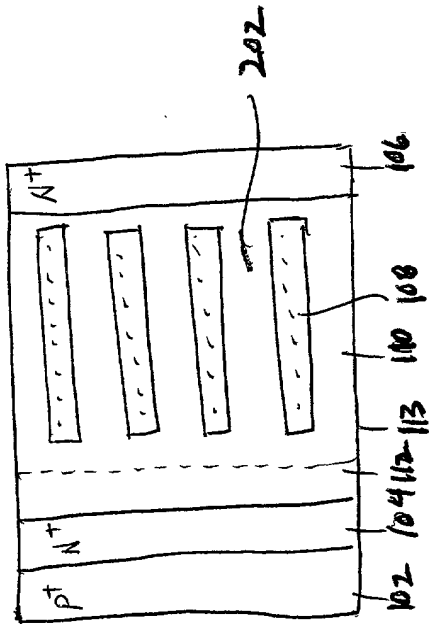


Fig. 4b

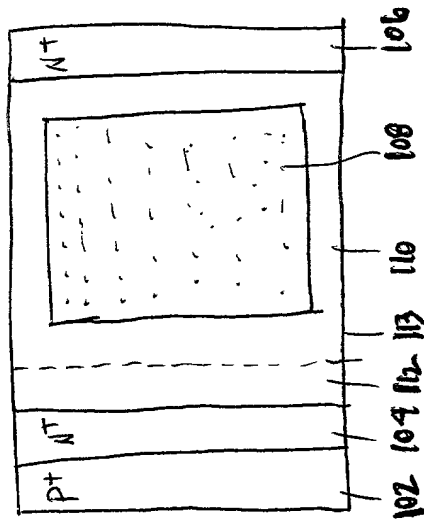


Fig. 4a

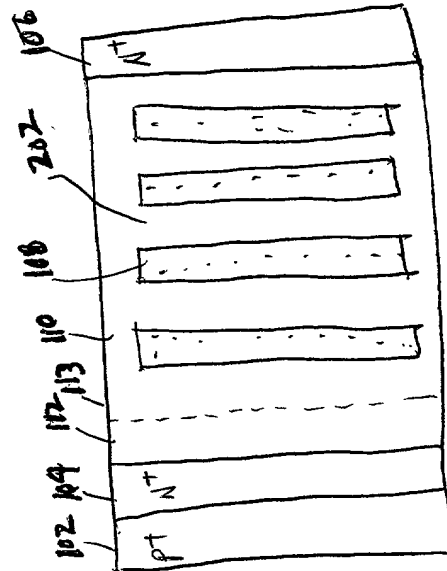


Fig. 4c

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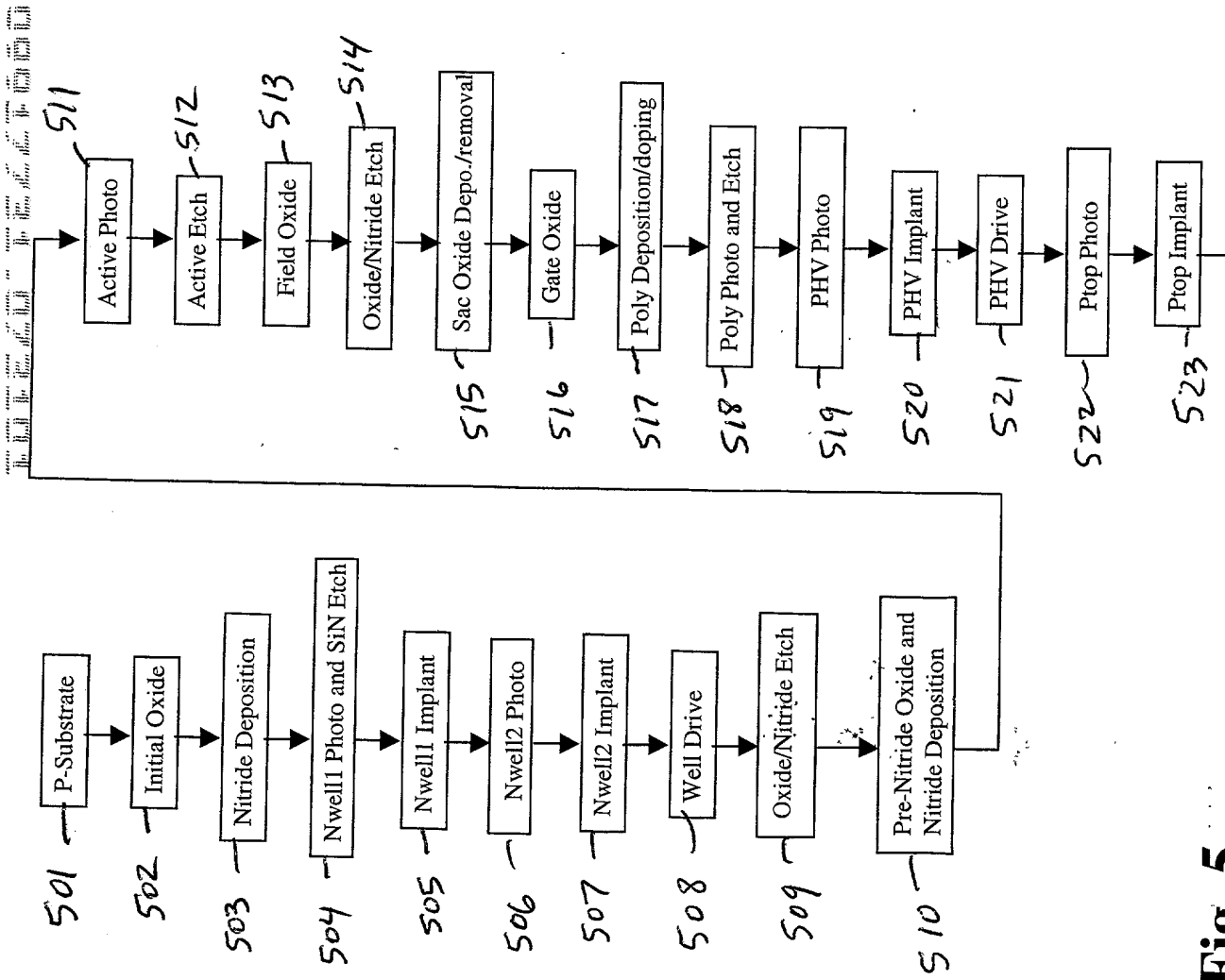


Fig. 5

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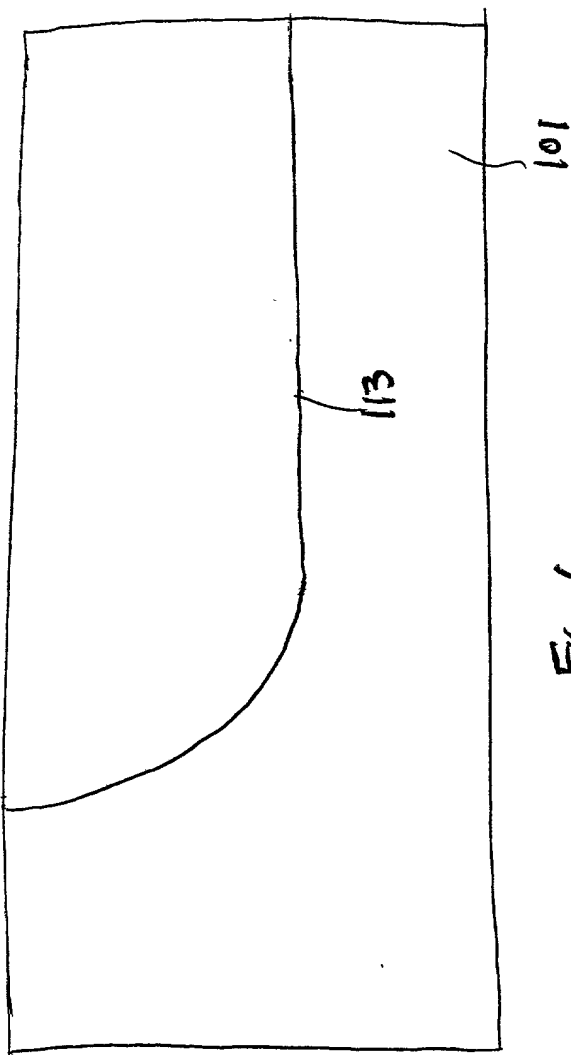


Fig 6

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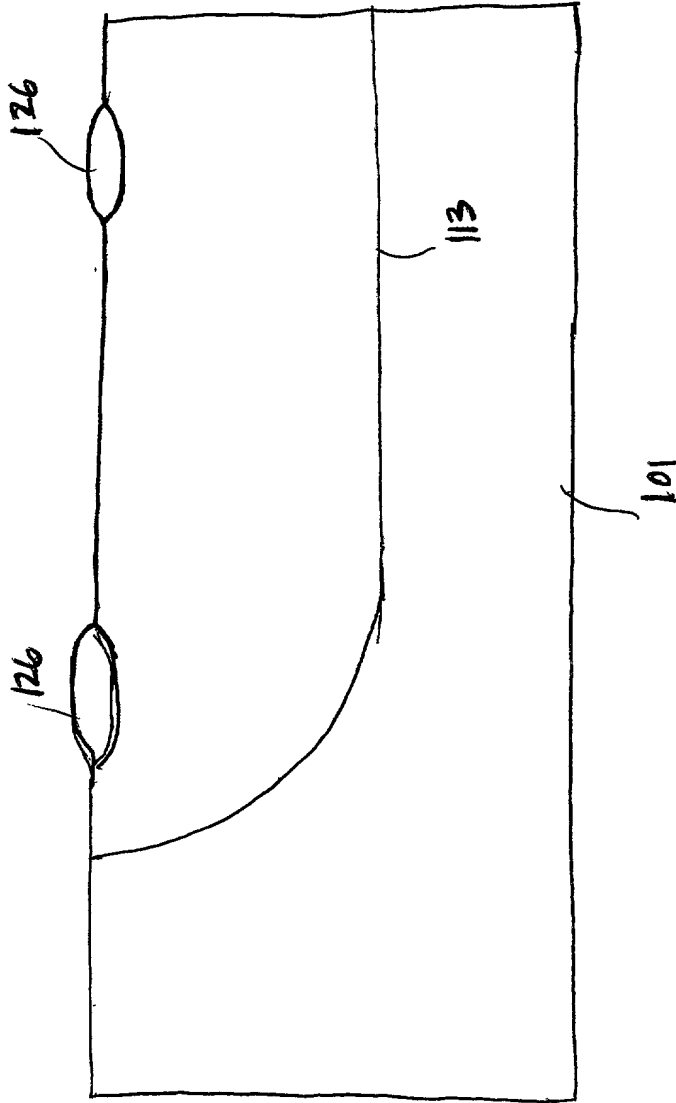


Fig. 7

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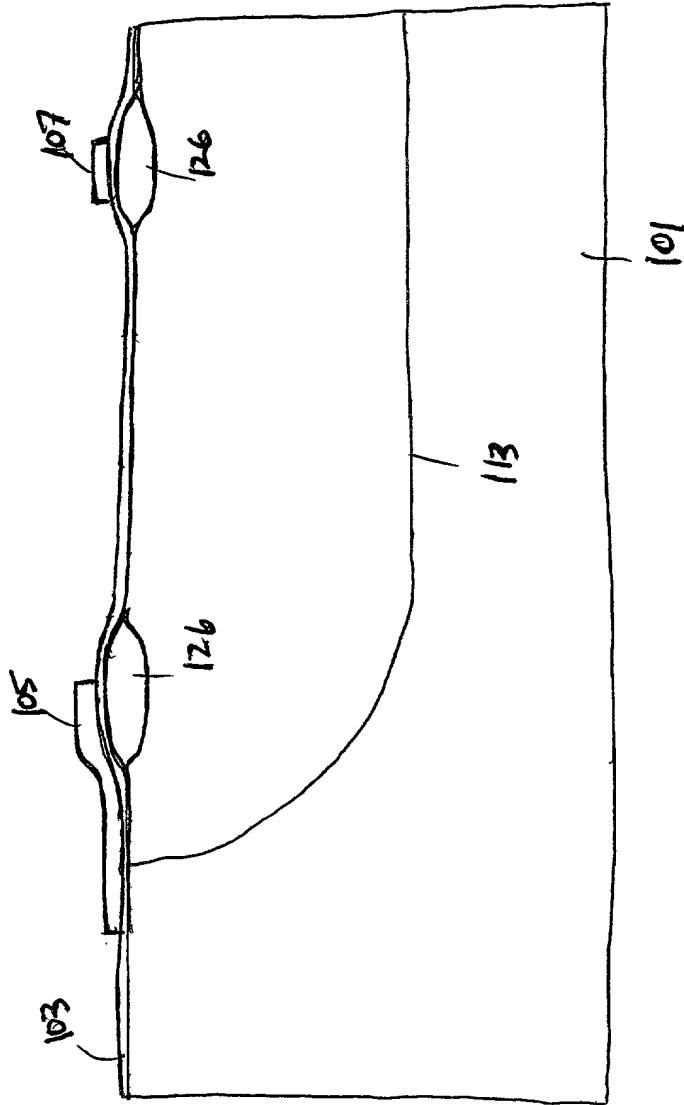


Fig 8

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Title: METHOD FOR MANUFACTURING A HIGH VOLTAGE MOSFET SEMICONDUCTOR DEVICE WITH ENHANCED CHARGE CONTROLABILITY  
 Atty dkt. No: ONS00187

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 1mAm et al.

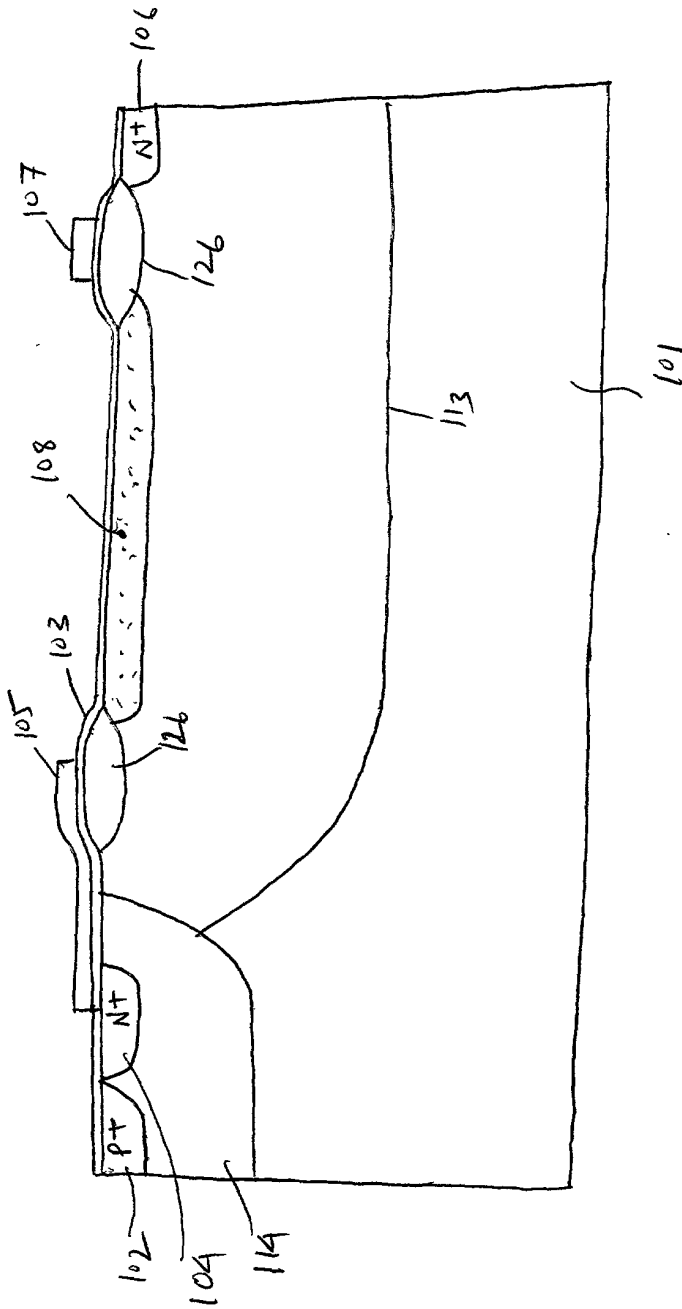


Fig. 10